

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-40	V
Collector-Emitter Voltage	V _{CE0}	-32	V
Emitter-Base Voltage	V _{EB0}	-5	V
Continuous Collector Current	I _C	-1	A
Peak Pulse Current	I _{CM}	-2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

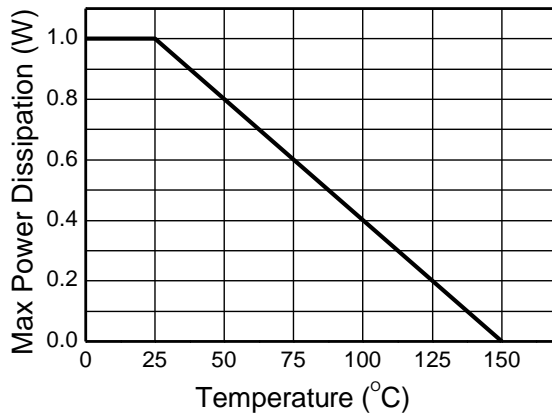
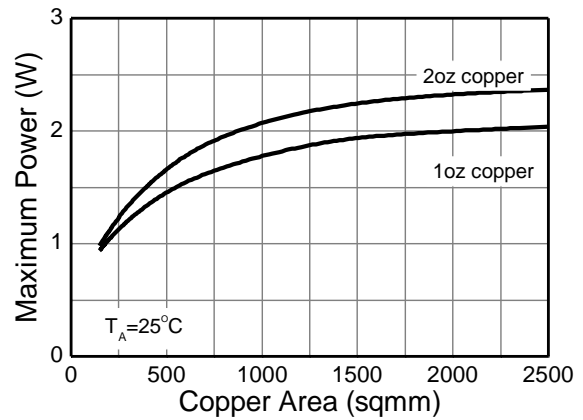
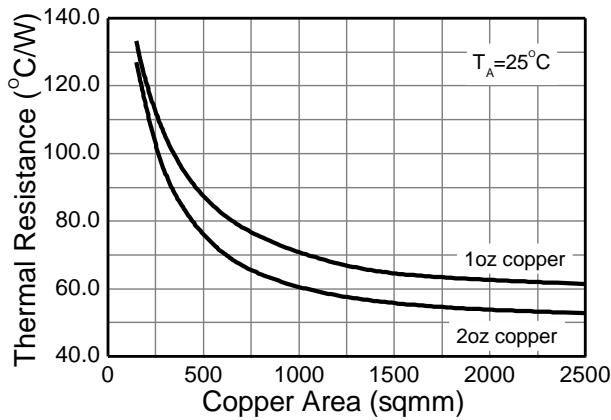
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	1	W
		1.5	
		2	
Thermal Resistance, Junction to Ambient Air	R _{θJA}	125	°C/W
		83	
		60	
Thermal Resistance, Junction to Case	R _{θJC}	18	°C/W
Thermal Resistance, Junction to Lead	R _{θJL}	22	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

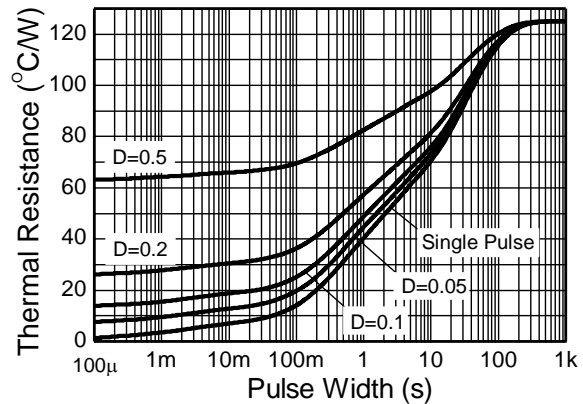
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
 - Thermal resistance from junction to solder-point (on the exposed collector pad).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

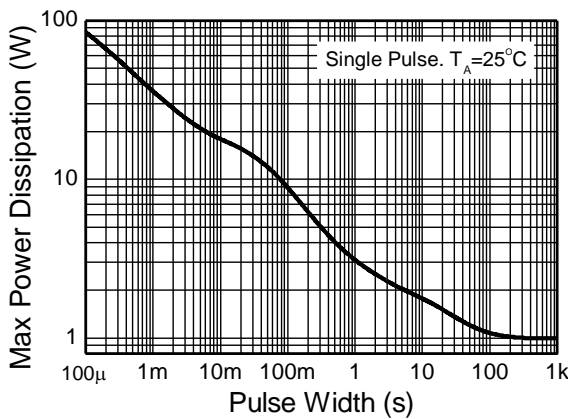
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-40	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-32	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	$I_E = -50\mu\text{A}$
Collector Cut-Off Current	I_{CBO}	—	—	-0.5	μA	$V_{CB} = -20\text{V}$
Emitter Cut-Off Current	I_{EBO}	—	—	-0.5	μA	$V_{EB} = -4\text{V}$
Static Forward Current Transfer Ratio (Note 10)	2DB1132P	82	—	180	—	$I_C = -100\text{mA}$, $V_{CE} = -3\text{V}$
	2DB1132Q	120		270		
	2DB1132R	180		390		
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	—	-125	-500	mV	$I_C = -500\text{mA}$, $I_B = -50\text{mA}$
Transition Frequency	f_T	—	190	—	MHz	$I_E = -50\text{mA}$, $V_{CE} = -5\text{V}$, $f = 30\text{MHz}$
Output Capacitance	C_{obo}	—	12	30	pF	$I_E = 0\text{A}$, $V_{CB} = -10\text{V}$, $f = 1\text{MHz}$

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

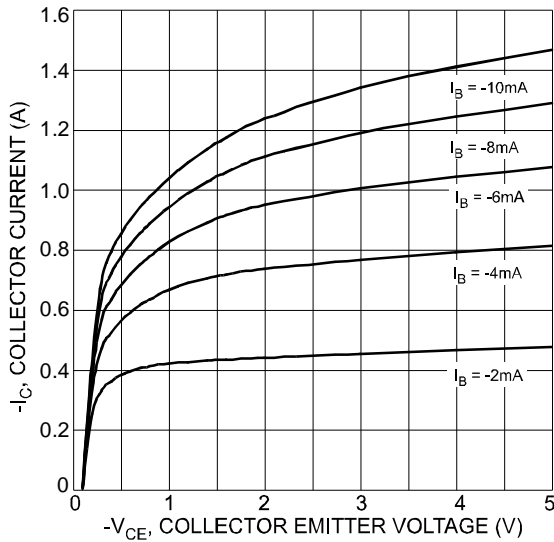


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

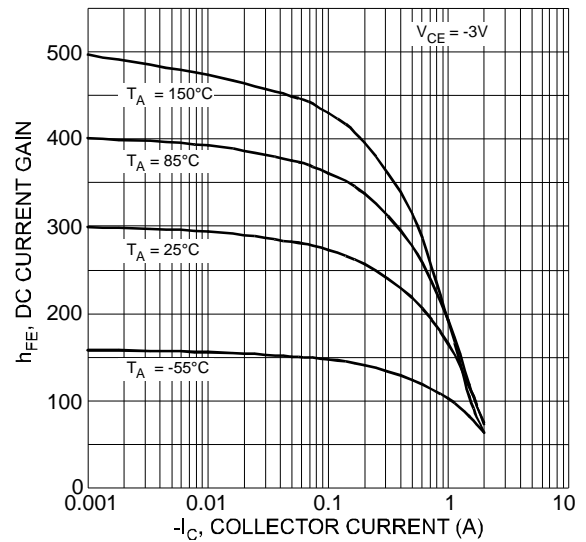


Fig. 2 Typical DC Current Gain vs. Collector Current (2DB1132R)

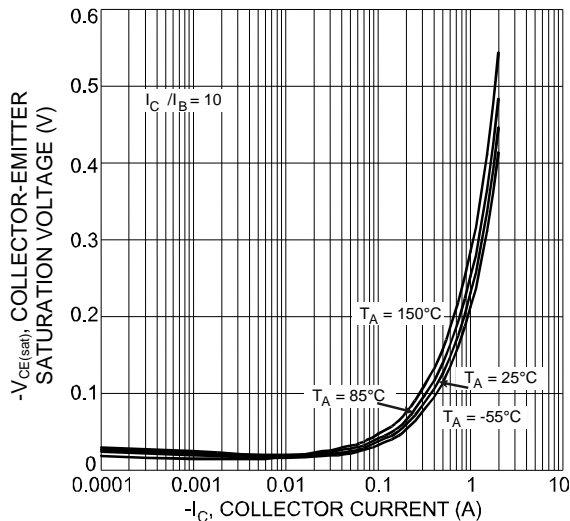


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

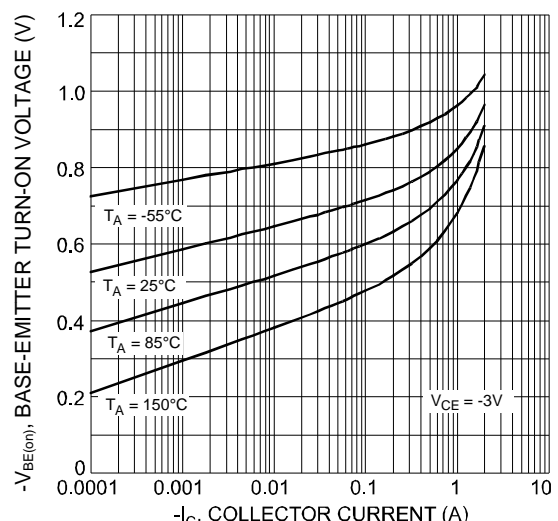
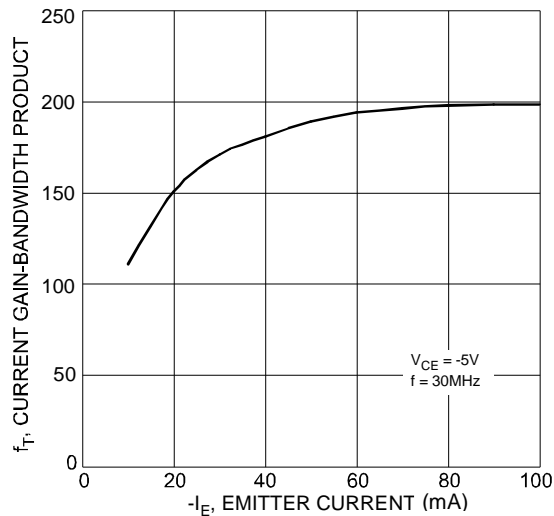
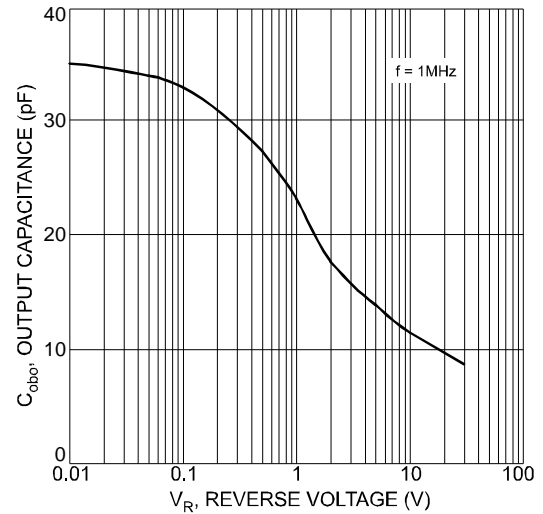
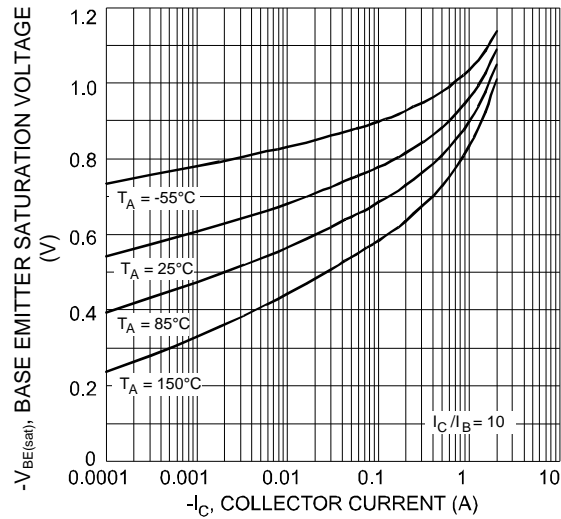


Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

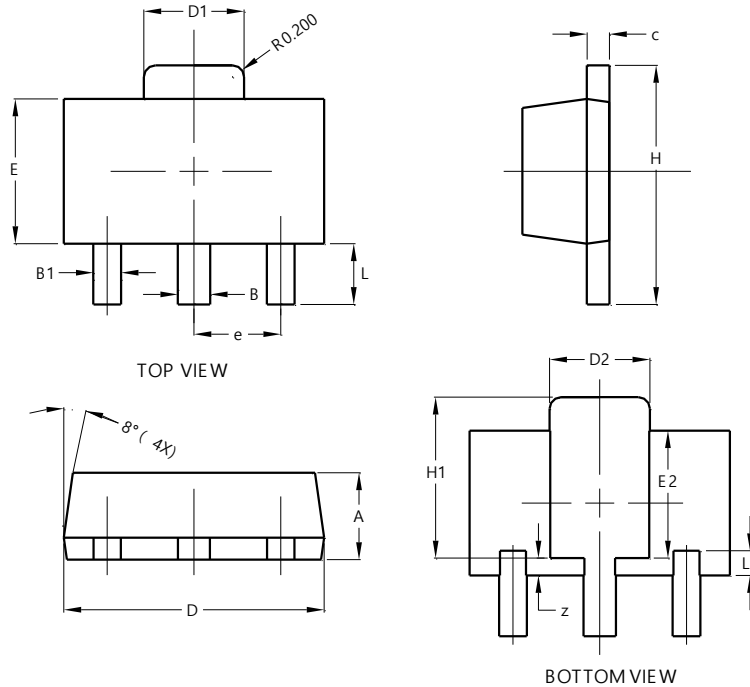
Typical Electrical Characteristics (continued) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT89

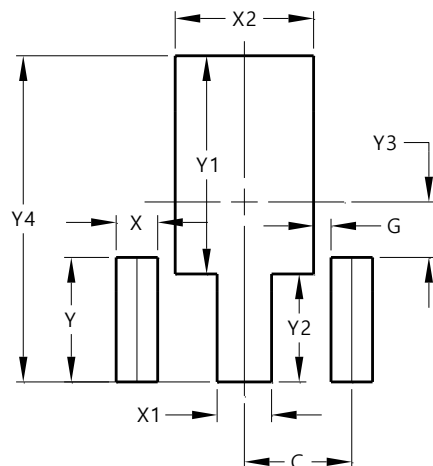


SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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